NSN 5961-01-042-1567

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-042-1567 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Terminal Length:** 0.312 inches **Overall Height:** Between 0.250 inches and 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 80.0 collector to base voltage, dc **Current Rating Per Characteristic:** Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

NSN 5961-01-042-1567 Transistor - Page 2 of 2



Fiig:

A110a0